

TECHNICAL DATA
Data Sheet 4098, Rev. D

Three-Phase IGBT BRIDGE, With Gate Driver and Optical Isolation

DESCRIPTION: A 600 VOLT, 80 AMP, THREE PHASE IGBT BRIDGE

ELECTRICAL CHARACTERISTICS PER IGBT DEVICE

(T_j=25°C UNLESS OTHERWISE SPECIFIED)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
IGBT SPECIFICATIONS					
Collector to Emitter Breakdown Voltage I _C = 250 μA, V _{GE} = 0V	BV _{CES}	600	-	-	V
Continuous Collector Current T _C = 25 °C T _C = 90 °C	I _C	-	-	80 70	A
Pulsed Collector Current, 1mS	I _{CM}	-	-	170	A
Gate to Emitter Voltage	V _{GE}	-	-	+/-20	V
Gate-Emitter Leakage Current , V _{GE} = +/-20V	I _{GES}	-	-	+/- 100	nA
Zero Gate Voltage Collector Current V _{CE} = 600 V, V _{GE} =0V T _J =25°C V _{CE} = 480 V, V _{GE} =0V T _J =125°C	I _{CES}	-	-	1 10	mA mA
Collector to Emitter Saturation Voltage, T _C = 25 °C I _C = 60A, V _{GE} = 15V,	V _{CE(SAT)}	-	1.7	2.0	V
Maximum Thermal Resistance	R _{θJC}	-	-	0.45	°C/W
Brake IGBT SPECIFICATIONS					
Continuous Collector Current T _C = 25 °C T _C = 90 °C	I _C	-	-	40 25	A
Pulsed Collector Current, 0.5mS	I _{CM}	-	-	120	A
Brake Resistor SPECIFICATIONS					
Maximum Continuous power dissipation	Pd			2	watt
Impulse Energy				80	Joules
Maximum operating Junction Temperature	T _{Jmax}	-40	-	150	°C
Maximum Storage Junction Temperature	T _{Jmax}	-55	-	150	°C

SENSITRON

TECHNICAL DATA

Data Sheet 4098, Rev. D

Over-Temperature Shutdown					
Over-Temperature Shutdown	Tsd	100	110	120	°C
Over-Temperature Output	Tso		10		10mV/°C
Over-Temperature Shutdown Hysteresis			20		°C

ULTRAFAST DIODES RATING AND CHARACTERISTICS					
Diode Peak Inverse Voltage	PIV	600	-	-	V
Continuous Forward Current, T _C = 90 °C	I _F	-	-	60	A
Forward Surge Current, t _p = 10 msec	I _{FSM}	-	-	300	A
Diode Forward Voltage, I _F = 60A	V _F	-	1.4	1.7	V
Diode Reverse Recovery Time (I _F =60A, V _{RR} =300V, di/dt=200 A/μs)	t _{rr}	-	90	160	nsec
Maximum Thermal Resistance	R _{θJC}	-	-	0.8	°C/W
Gate Driver					
Supply Voltage	VCC	10	15	20	V
Input On Current	HIN, LIN	2		5.0	mA
Opto-Isolator Logic High Input Threshold	I _{th}	-	1.6	-	mA
Input Reverse Breakdown Voltage	BV _{in}	5.0	-	-	V
Input Forward Voltage @ I _{in} = 5mA	V _F	-	1.5	1.7	V
Under Voltage Lockout	VCCUV	11.5	-	12.5	V
ITRIP Reference Voltage ⁽¹⁾	Itrip-ref	2.9	3.0	3.1	V
Input-to-Output Turn On Delay	t _{ond}	-		800	nsec
Output Turn On Rise Time	t _r	-		100	
Input-to-Output Turn Off Delay	t _{offd}	-			
Output Turn Off Fall Time	t _f	-		1000	
@ VCC=300V, IC=50A, T _C = 25				100	
Input-Output Isolation Voltage	-	1000	-	-	V

(1) ITRIP Cycle-by cycle current limit is internally set to 70A peak. The set point can be lowered by connecting a resistor between Itrip-ref and Gnd. The set point can be increased by connecting a resistor between Itrip-ref and +5V ref

SENSITRON**TECHNICAL DATA****Data Sheet 4098, Rev. D****Pin Description**

Pin Number	Function	Pin Number	Function
1	Isolated Input for Low-side IGBT of Phase A	17	+15V Rtn (Signal Ground)
2	Return for Input at 1	18	Fault Output ⁽³⁾
3	Isolated Input for High-side IGBT of Phase A	19	Fault Clear Input ⁽³⁾
4	Return for Input at 3	20	+5V Output
5	Isolated Input for Low -side IGBT of Phase B	21	Over-Current Trip Set point ⁽³⁾
6	Return for Input at 5	22	DC Bus Current Output with Total Gain of 0.0365 V/A
7	Isolated Input for High-side IGBT of Phase B	23	Case Temperature Output with a gain of 0.010 V/°C
8	Return for Input at 7	24	Brake IGBT Gate Input
9	Isolated Input for Low-side IGBT of Phase C	25	Brake IGBT Emitter Input. This input is internally connected to Signal Ground
10	Return for Input at 9	26 to 30	DC Bus return
11	Isolated Input for High-side IGBT of Phase C	31 , 32	Brake Resistor Terminal. Brake Resistor Shall be Connected Between These Terminals and +VDC
12	Return for Input at 11	33 to 37	DC Bus "+VDC" input
13	NC	38 to 42	Phase C output
14	NC	43 to 47	Phase B output
15	SD ⁽³⁾	48 to 52	Phase A output
16	+15V Input	Case	Isolated

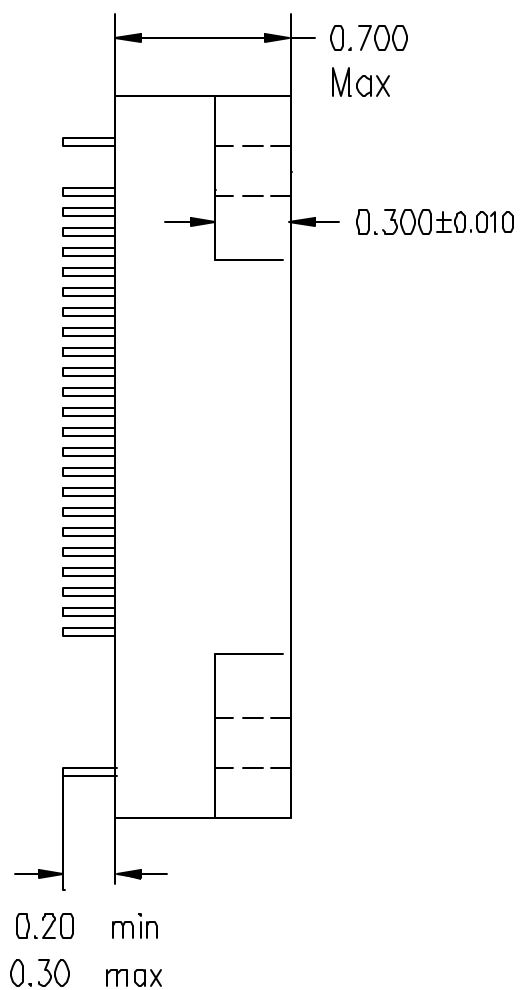
This is a detailed mechanical drawing of a PCB layout. It shows the dimensions and positions of various components and features. The drawing includes the following dimensions and labels:

- Dimensions:**
 - 0.657±0.020
 - 0.185±0.020
 - 0.390±0.020
 - 0.140±0.020
 - 0.300±0.020
 - 0.165±0.010
 - 0.165±0.010
 - 0.220±0.020
 - 0.080±0.010
 - 0.160±0.010
 - 0.480±0.010
 - 0.240±0.010
 - 0.160±0.010
 - 0.245±0.020
 - 0.185±0.020
 - 0.400±0.020
 - 2.900±0.020
 - 2.300±0.020
 - 2.300±0.020
 - 0.200±0.020
 - 2.900±0.020
 - 3.300±0.020
 - 3.700±0.020
 - ∅0.200±0.020
- Component Labels:**
 - PhC...PhC 38 42
 - PhB...PhB 43 47
 - PhA...PhA 48 52
 - LinA 1
 - LinA-Rtn 2
 - LinA 3
 - LinA-Rtn 4
 - LinB 5
 - LinB-Rtn 6
 - LinB 7
 - LinB-Rtn 8
 - LinC 9
 - LinC-Rtn 10
 - LinC 11
 - LinC-Rtn 12
 - NC 13
 - NC 14
 - SD 15
 - +15V 16
 - +15V Rtn 17
 - Flt 18
 - Flt Clr 19
 - +5V-out 20
 - I trip-ref 21
 - Ido 22
 - Tco 23
 - +V...+V 37 33
 - Brk 32 31
 - +VRtn...+VRtn 30 26
 - Ebrk 25
 - Gbrk 24

TECHNICAL DATA

Data Sheet 4098, Rev. D

Package Drawing Side View:



SENSITRON**TECHNICAL DATA****Data Sheet 4098, Rev. D**

Application Notes:**a- Shutdown Feature:**

- 1- SD is a dual function input/output, active low input. It is internally pulled high. As a low input shuts down all IGBTs regardless of the Hin and Lin signals.
- 2- SD is also internally activated by the over-temperature shutdown, over-current limit, under-voltage shutdown, and desaturation protection.
- 3- Over-temperature shutdown, and over-current limit are not latching features.
- 4- Under-voltage shutdown is automatically reset after 300 msec once the VCC rises above the threshold limit.
- 5- Desaturation shutdown is a latching feature and internally reset after 300 msec.
- 6- When any of the internal protection features is activated, SD is pulled down.
- 7- SD can be used to shutdown all IGBTs except the brake IGBT by an external command. An open collector switch shall be used to pull down SD externally.
- 8- Also, SD can be used as a fault condition output. Low output at SD indicates a fault situation.

b- Fault Output Feature:

- 1- Pin 18 Flt is a dual function pin. It is internally pulled high. If pulled down, it will freeze the status of all the six IGBTs regardless of the Hin and Lin signals
- 2- Pin 18 as an output reports desaturation protection activation. When desaturation protection is activated a low output for about 9 μ sec is reported.
- 3- If any other protection feature is activated, it will not be reported by Pin 18.

c- Fault Clear Output:

- 1- Pin 19 is a fault clear input. It can be used to reset a latching fault condition, due to desaturation protection.
- 2- Pin 19 is internally pulled down. A latching fault due to desaturation can be cleared by pulling high this input.
- 3- An internal fault clear is activated after 300 msec delay. If desired to clear the fault earlier, this input can be used.